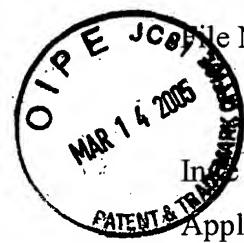


IPW



File No. 14836-8US-1 AD/mb

Montreal, Canada

March 9, 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In the Application of:

Applicant: MICROBRIDGE TECHNOLOGIES INC.

Serial No.: 10/796,421

Filed: March 10, 2004

Title: METHOD FOR TRIMMING RESISTORS

Group Art Unit: 3742

Examiner: --

Agent of Record: Alexandra Daoud Tel: (514) 847-4333

MAIL STOP – AMENDMENTS
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SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

PRIOR TO FIRST OFFICE ACTION

Sir:

Pursuant to the duty of disclosure under 37 CFR 1.56, copies of the references listed on the attached PTO Form SB08A/B are submitted herewith.

In accordance with 37 CFR 1.97(h), the submission of the present information is not to be construed as an admission that such information is, or is considered to be material to patentability.

The Examiner is kindly requested to consider these references during the examination of the above-identified application, making the references of record, and to return an initialed copy of the SB08A/B Form to the below-signed agent.

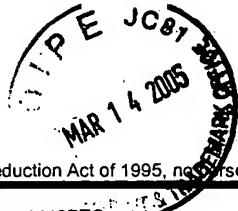
Respectfully submitted,

MICROBRIDGE TECHNOLOGIES INC.

By:


Alexandra Daoud, Registration No. 55,992
OGILVY RENAULT
Customer Number 020988

Enc.: Copies of references cited therein
2 sets of SB08A/B Form



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<p>Substitute for form 1449PTQ</p> <p>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p><i>(use as many sheets as necessary)</i></p>				<p><i>Complete if Known</i></p>	
				Application Number	10/796, 421
				Filing Date	March 10, 2004
				First Named Inventor	Oleg GRUDIN et al.
				Art Unit	3742
				Examiner Name	(unknown)
Sheet	1	of	3	Attorney Docket Number	14836-8US-1 AD/mb

#U.S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

Examiner Signature		Date Considered	
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(use as many sheets as necessary)				Filing Date	March 10, 2004
				First Named Inventor	Oleg GRUDIN et al.
				Art Unit	3742
				Examiner Name	(unknown)
Sheet	2	of	3	Attorney Docket Number	14836-8US-1 AD/mb

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
		Constant Voltage Trimming of Heavily Doped Polysilicon Resistors, Japan Journal Appl. Phys. Vol. 34, Part 1, No. 1, January 1995, pp. 48-53.	
		Pulse Current Trimming of Polysilicon Resistors, Transactions of Electron Devices, IEEE, Vol. 42, N° 4, April 1995, pp. 689-695.	
		Change in Temperature Coefficient of Resistance of Heavily Doped Polysilicon Resistors Caused by Electrical Trimming, Japan Journal Appl. Phys., Vol. 35, Part 1, No. 8, August 1995, pp. 4209-4215.	
		Theory and Application of Polysilicon Resistor Trimming, Solid-State Electronics, Vol. 38, N° 11, 1995, pp. 1861-1869.	
		Electrical Trimming of Ion-Beam Sputtered Polysilicon Resistors by High Current Pulses, IEEE Transactions on Electron Devices, Vol. 41, No. 8, August 1994, pp. 1429-1434.	
		Electrical Trimming of Heavily Doped Polycrystalline Silicon Resistors, IEEE Transactions on Electron Devices, Vo. ED-26, No. 11, November 1979, pp. 738-742.	
		A Monolithic 14Bit D/A Converter Fabricated with a New Trimming Technique (DOT), IEEE, Journal of Solid-State Circuits, Vol. SC-19, N° 5, October 1984, pp. 802-807.	
		Precision Electrical Trimming of Very Low TCR Poly-SiGe Resistors, IEEE Electron Device Letters, Bol. 21, No. 6, June 2000, pp. 283-286.	
		1/f Noise Transformation that Accompanies the Trimming of Polycrystalline Silicon Layers, Solid State Phenomena, Vols. 51-52 (1996) Scitec Publications, Switzerland, pp. 391-396.	
		Micromachined Thermal Radiation Emitter from a Commercial CMOS Process, IEEE Electron Devices Letters, Vol. 12, No. 2, February 1991, pp. 57-59.	

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Substitute for form 1449PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Application Number	10/796, 421
Sheet	3	of	3	Filing Date	March 10, 2004
				First Named Inventor	Oleg GRUDIN et al.
				Art Unit	3742
				Examiner Name	(unknown)
				Attorney Docket Number	14836-8US-1 AD/mb

NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published		T ²
		CMOS-Compatible High-Temperature Micro-Heater: Microstructure Release and Testing, Can. J. Elect & Comp. Eng., Vol. 25, No. 1, January 2000, pp. 002-006.		
		Reliability Study of Polysilicon for Microhotplates, 1994, Dept. of Electrical and Computer Engineering, N.R. Swart et al., University of Waterloo, Waterloo, Ont. CANADA, pp. 119-122.		
		CMOS Thermally Isolated Heater Structure as a Substrate for Semiconductor Gas Sensors, S. Wessel et al, Energy Research Institute, pp. 1.6.1 to 1.6.8.		
		A Microstructure for Measurement of Thermal Conductivity of Polysilicon Thin Films, Friedemann Völklein et al., Jour. of Microelectromechanical Systems, Vol. 1, N° 4, Dec. 1992, pp. 193-196.		
		Electrical and Optical Characteristics of Vacuum-Sealed Polysilicon Microlamps, Carlos H. Mastrangelo et al., IEEE Transactions on Electron Devices, Vol. 39, N° 6, June 1992, pp. 1363-1374.		

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